## NSN 5961-01-308-6670

Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.290 inches
Terminal Length:
Between 0.240 inches and 0.370 inches
Overall Height:
Between 0.030 inches and 0.085 inches
Overall Width:
Between 0.240 inches and 0.260 inches
Component Name And Quantity:
8 semiconductor device diode
Mounting Method:
Terminal
Terminal Circle Diameter:
Between 0.010 inches and 0.019 inches
Semiconductor Material:
Silicon all semiconductor device diode
Voltage Rating In Volts Per Characteristic:
60.0 reverse breakdown voltage, dc all semiconductor device diode
Current Rating Per Characteristic:
300.00 milliamperes peak forward surge current megahertz all semiconductor device diode
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
10 pin
Specification Data:
81349-mil-s-19500/474 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Filg:

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